

PATENT
Customer No. 22,852
Attorney Docket No. 04329.2344-02

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:)
)
Kyoichi SUGURO et al.) Prior Group Art Unit: 2822
)
Divisional of Appln. No.: 09/609,107) Prior Examiner: Michael M. Trinh
)
Filed: Herewith)
)
For: SEMICONDUCTOR DEVICE AND)
METHOD FOR MANUFACTURING)
THE SAME)

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. § 1.97(b)

Pursuant to 37 C.F.R. §§ 1.56 and 1.97(b), Applicants bring to the attention of the Examiner the documents listed on the attached PTO 1449. This Information Disclosure Statement is being filed concurrently with the above-referenced divisional application.

Copies of the listed documents were previously submitted by Applicants or cited by the Examiner in prior Application No. 09/609,107, filed on June 30, 2000, upon which Applicants rely for the benefits provided in 35 U.S.C. § 120. Applicants respectfully request that the Examiner consider the listed documents and indicate that they were considered by making appropriate notations on the attached form.

The following is a concise statement of relevance of the non-English language document:

1. Japanese Patent Application No. 11-26574 discloses a contact plug structure and method which uses single crystal Si epitaxial growth in a contact hole. In the epitaxial Si film, there is no active device such as a transistor and the epitaxial Si film is doped with n type or p type impurity atoms so heavily that the electrode and the Si film contact have low contact resistivity.

This submission does not represent that a search has been made or that no better art exists and does not constitute an admission that each or all of the listed documents are material or constitute "prior art." If the Examiner applies any of the documents as prior art against any claim in the application and Applicants determine that the cited documents do not constitute "prior art" under United States law, Applicants reserve the right to present to the Office the relevant facts and law regarding the appropriate status of such documents.

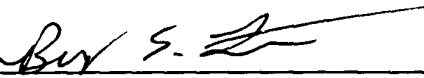
Applicants further reserve the right to take appropriate action to establish the patentability of the disclosed invention over the listed documents, should one or more of the documents be applied against the claims of the present application.

If there is any fee due in connection with the filing of this Statement, please charge the fee to our Deposit Account No. 06-0916.

Respectfully submitted,

FINNEGAN, HENDERSON, FARABOW,
GARRETT & DUNNER, L.L.P.

Dated: July 22, 2003

By: 
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INFORMATION DISCLOSURE CITATION

Atty. Docket No.	04329.2344-02	Div. of Appln. No.	09/609,107
Applicant	Kyoichi SUGURO et al.		
Filing Date	Herewith	Prior Group:	2822

U.S. PATENT DOCUMENTS							
Examiner Initial*		Document Number	Issue Date	Name	Class	Sub Class	Filing Date If Appropriate
		5,534,459	07/1996	Kim			
		5,950,097	09/1999	Chang et al.			
		5,963,822	10/1999	Saihara et al.			
		5,895,248	04/1999	De Boer et al.			
		6,326,293	12/2001	Fang et al.			

FOREIGN PATENT DOCUMENTS							
		Document Number	Publication Date	Country	Class	Sub Class	Translation Yes or No
		11-26574	01/1999	Japan			No

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)	

Examiner	Date Considered
*Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	
Form PTO 1449	Patent and Trademark Office - U.S. Department of Commerce